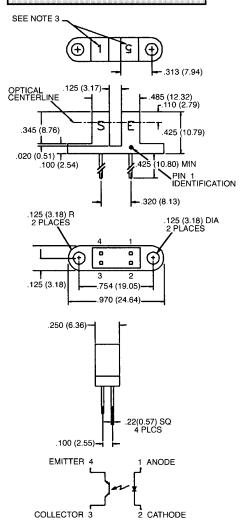


SLOTTED OPTICAL SWITCH

OPB860T11/OPB860T51/OPB860T55

PACKAGE DIMENSIONS



ST1782

NOTES:

- 1. DIMENSIONS ARE IN INCHES (mm).
- TOLERANCE IS ±.010 (.25)
 UNLESS OTHERWISE SPECIFIED.
- 3. NUMBER INDICATES APERTURE SIZE. (5=.050'', 1=.010'')

APERTURE OPTIONS:

ALLINOIL OF IT	ONO.	
	LED	PHOTOTRANSISTOR
OP8860T11	.010	.010
OP8860T51	.050	.010
OP8860T55	.050	.050

DESCRIPTION

The OPB860T series of switches is designed to allow the user maximum flexibility in applications. Each switch consists of an infrared emitting diode facing an NPN phototransistor across a .125" (3.18mm) gap. A unique housing design provides a smooth external surface to prevent dust build-up while molded internal apertures give precise positioning and also provide protection from ambient light interference.

FEATURES

- Fully enclosed design allows dust protection.
- Lead spacing at .320".
- .050" and .010" aperture options.
- PCB mountable.



SLOTTED OPTICAL SWITCH

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C Unless Otherwise Sp	pecified)
Storage Temperature Operating Temperature Soldering:	
Lead Temperature (Iron) Lead Temperature (Flow)	
INPUT DIODE Continuous Forward Current	50 m∆
Continuous Forward Current Reverse Voltage Power Dissipation	5.0 Volts 100 mW ⁽¹⁾
OUTPUT TRANSISTOR Collector-Emitter Voltage Emitter-Collector Voltage Power Dissipation	

PARAMETER	SYMBOL	MIN.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE					
Forward Voltage	$V_{\scriptscriptstyle F}$		1.70	V	$I_{\rm F}=20~{\rm mA}$
Reverse Leakage Current	I _R	_	100	μΑ	V _R = 2.0 V
OUTPUT TRANSISTOR					
Emitter-Collector Breakdown	BV_{eco}	5	_	V	$I_E = 100 \mu A$, $Ee = 0$
Collector-Emitter Breakdown	BV _{CEO}	30		V	$I_c = 1.0 \text{ mA, Ee} = 0$
Collector-Emitter Leakage	I _{CEO}	_	100	nA	$V_{CE} = 10.0 \text{ V}, \text{ Ee} = 0$
COUPLED	- 5-00				
On-State Collector Current					
OPB860N11	I _{C(ON)}	500	_	μΑ	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$
OPB860N51	I _{C(ON)}	500	_	μΑ	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$
OPB860N55	I _{C(ON)}	500	_	μΑ	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$
Saturation Voltage	V _{GE(SAT)}		0.40	V	$I_{\rm F} = 20 \text{mA}, I_{\rm C} = 400 \mu$

NOTES

- Derate power dissipation linearly 1.67 mW/°C above 25°C.
 RMA flux is recommended.
 Methanol or Isopropyl alcohols are recommended as cleaning agents.
 Soldering iron tip 1/6" (1.6 mm) from housing.



SLOTTED OPTICAL SWITCH

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.